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# Brilliance Scaling of Discharge based EUV and soft X-Ray Sources

Klaus Bergmann, Fraunhofer Institute for Laser Technology, Aachen, Germany  
Source Workshop, 13-15 November, Dublin

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# Overview

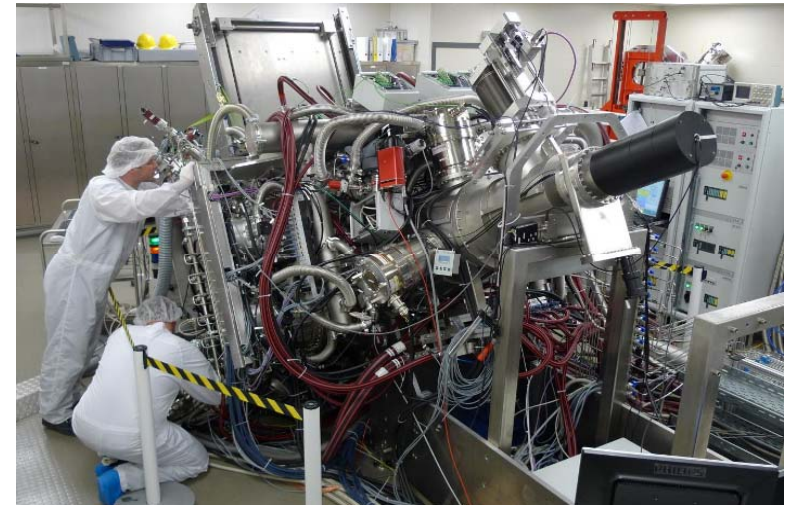
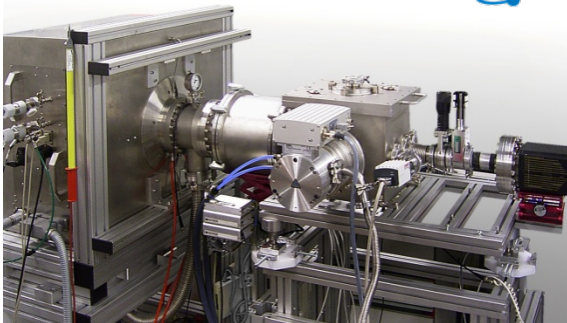
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- Introduction
- Investigations on brilliance for pseudo-spark based discharge source at ILT
- State of the art for:
  - 2.9 nm into single line : soft x-ray microscopy
  - 10.9 nm into 4% b.w. : interference lithography
  - 13.5 nm into 2% b.w. : environment of EUV lithography
- Outlook on brilliance scaling potential
- Conclusions

# Current XUV activities at ILT

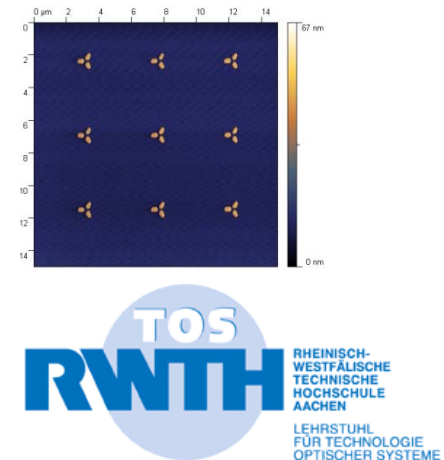
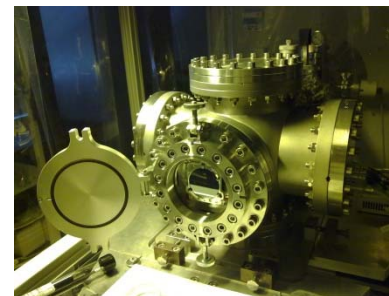
- Development of sources for EUV lithography based on tin vacuum arc (together with Xtreme)
- Sources for metrology in the range soft x-ray and EUV
- XUV-Applications (\*)  
(Support of TOS, RWTH Aachen University)

X-ray microscopy



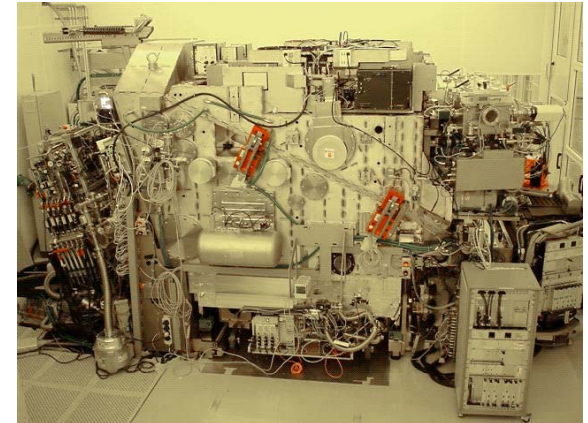
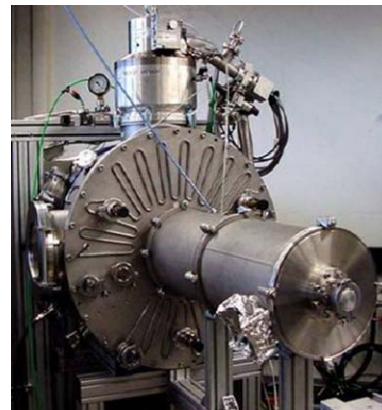
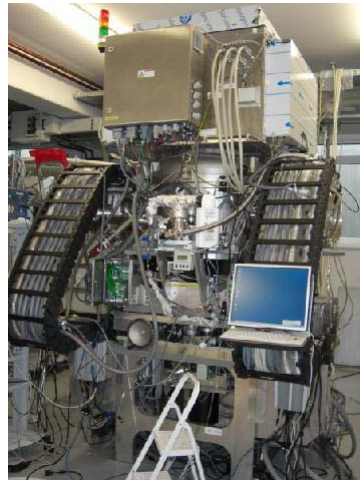
EUVL source development

Interference lithography



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# Discharge XUV sources are in commercial use . . .

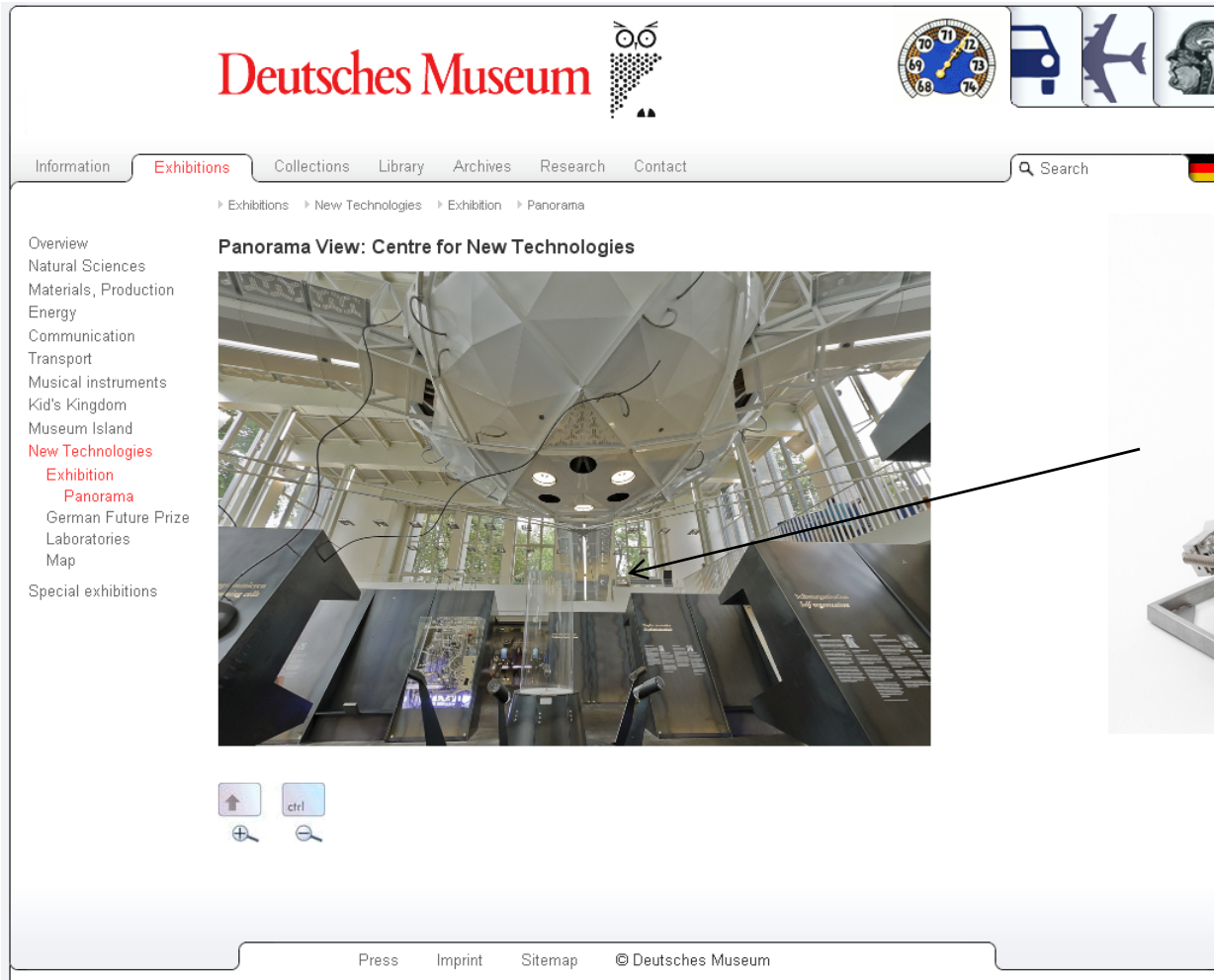


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# ...and also already in museum



Fraunhofer  
ILT  
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<http://www.deutsches-museum.de/en/exhibitions/new-technologies>

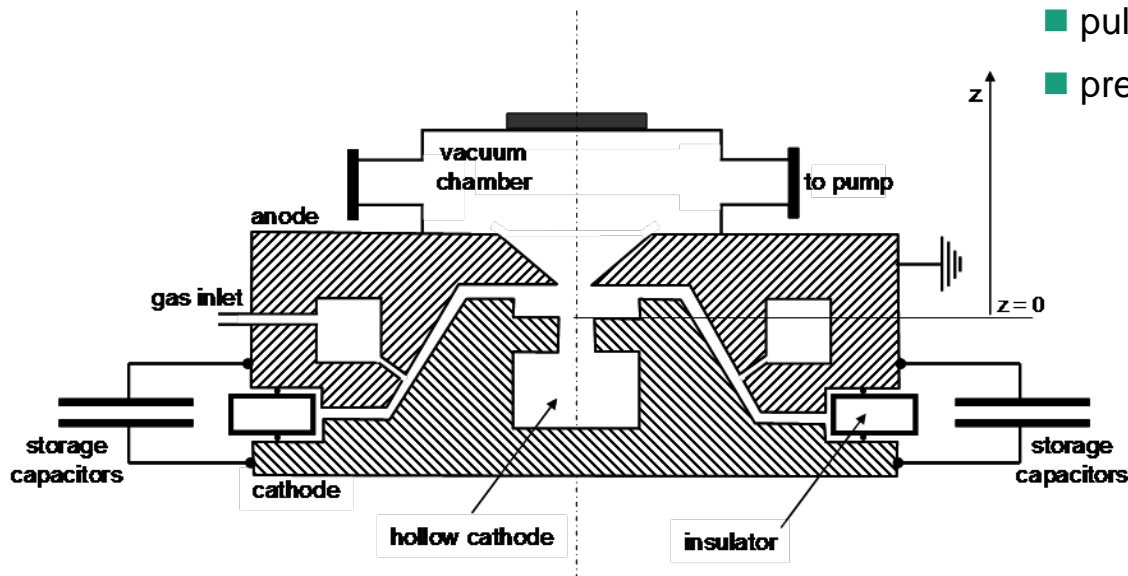
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# Pseudospark based discharge source

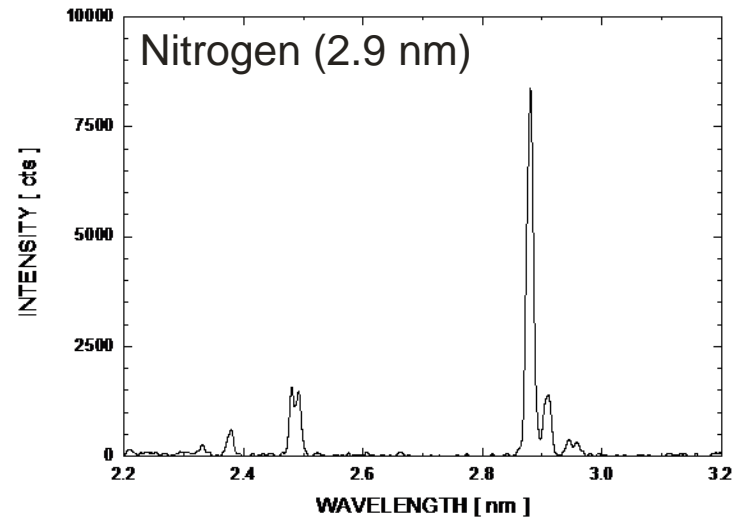
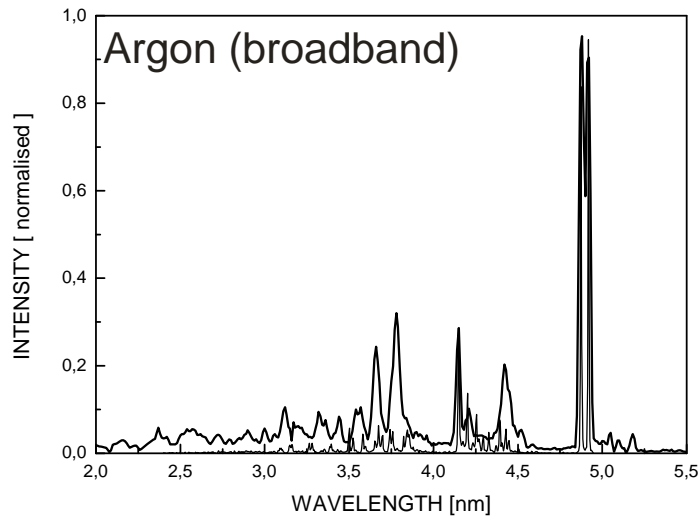
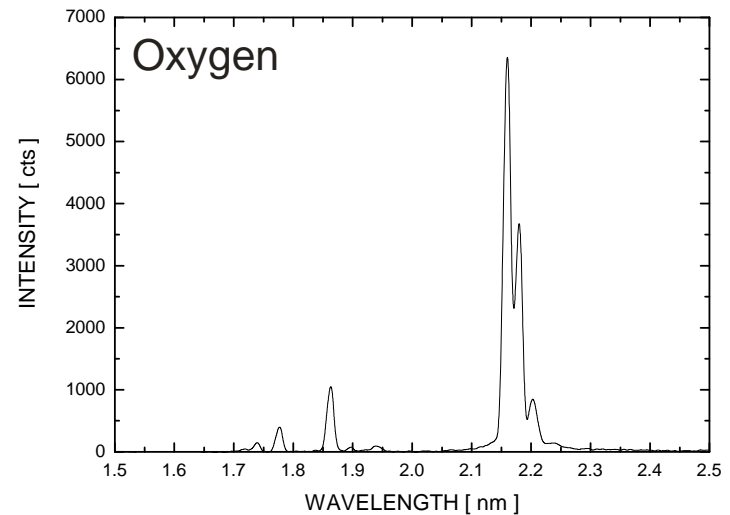
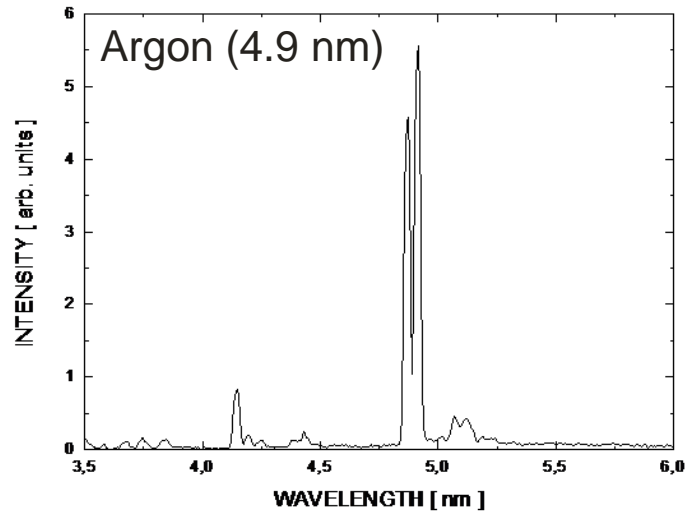
## Typical device parameters

■ capacity	: 100 nF to few $\mu\text{F}$
■ pulse energy	: 2 - 20 J
■ inductance	: $\sim 10\text{-}14$ nH
■ peak current	: up to 40 kA
■ pulse duration	: few 100 ns
■ pressure	: several 10 Pa (dependent on gas)

## Scheme of electrode system

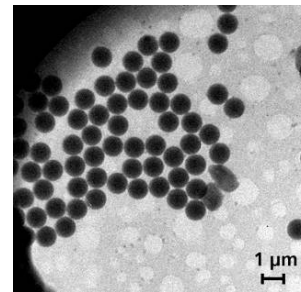
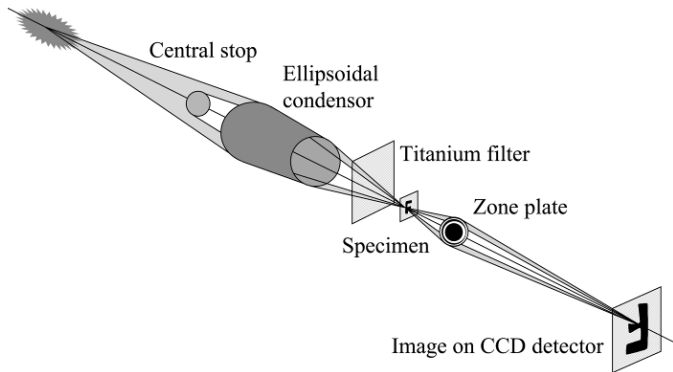
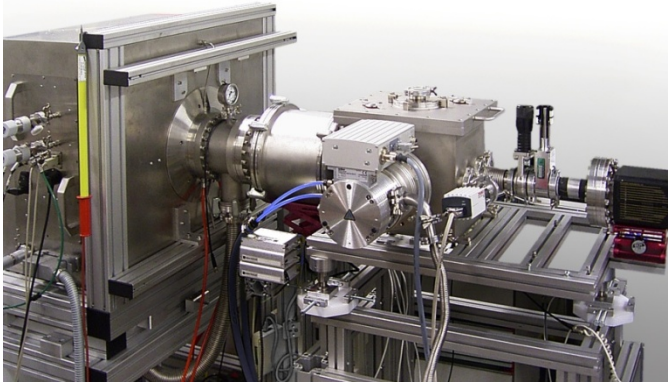


# Emission spectra (soft x-ray)



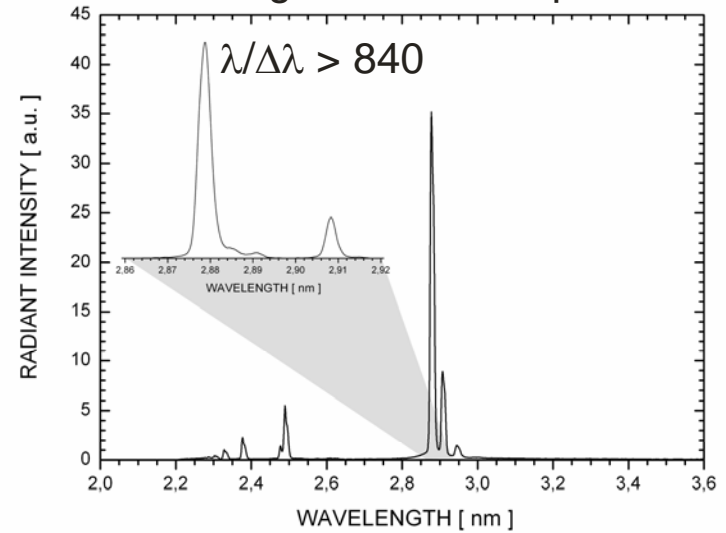


# Soft x-ray microscopy

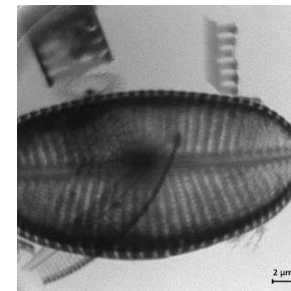


Latex-Spheres

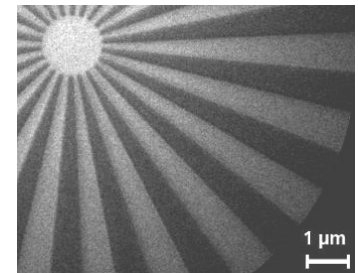
Nitrogen emission spectrum



- brilliance :  $2 \cdot 10^9 \text{ Ph}/(\mu\text{m}^2 \text{ sr s})$
- total emission:  $15 \text{ W}/(2\pi\text{sr})$   
at 2.88nm (430 eV)
- input power : 20 kW at 1 kHz



Diatoms



Siemens star

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# Platform for brilliance measurements (EUV)

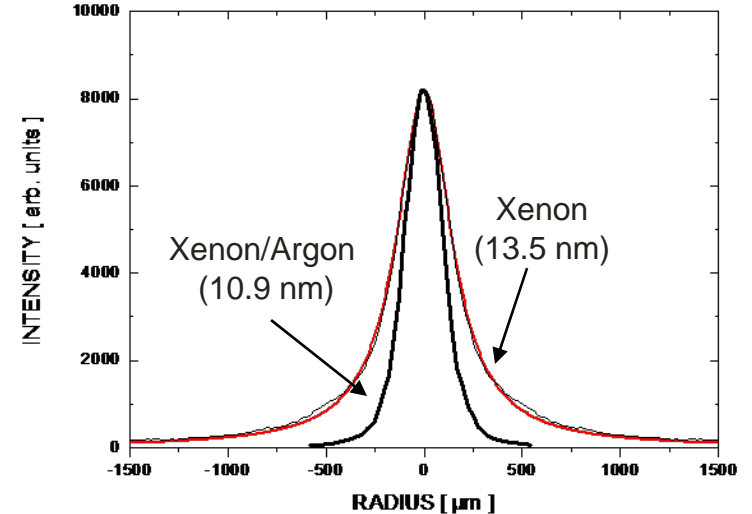
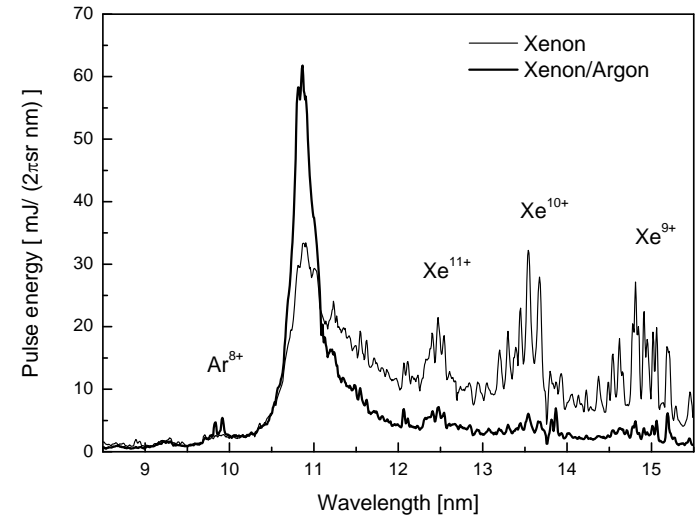
- Xenon based technology developed by Philips for EUV lithography
- input power : max. 10 kW
- pulse energy : max. 3 J
- repetition rate : max. 3 kHz
- operational with different gases



 **Fraunhofer**  
ILT **PHILIPS**

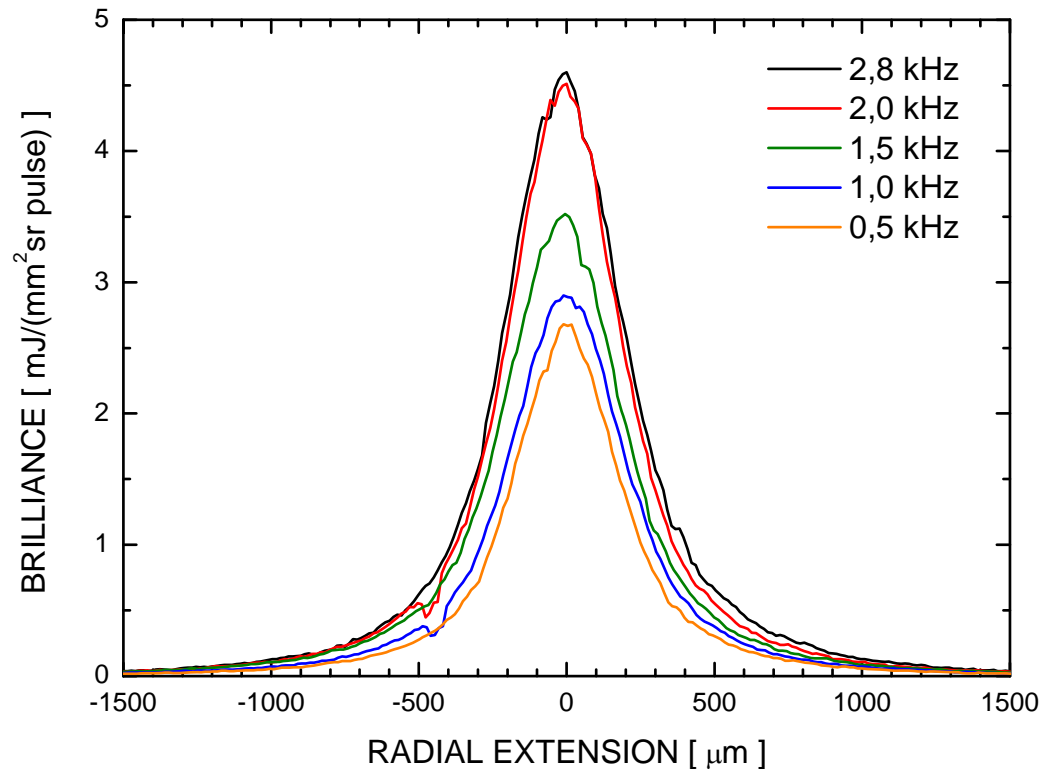
# Brilliance for optimization around 11 nm

- suppression of optically thin Xe transitions by dilution with Argon:
  - ~ 11 nm : optically thick 4f-4d transitions
  - ~ 12-16 nm: optically thin 5p-4d transitions
- increase of brightness at 11 nm due to better discharge conditions with Argon
- discharge parameters:
  - frequency : 2000 Hz
  - pulse energy : 2.8 J
  - input power : 5.6 kW
- emission around 11 nm into 4% b.w.:
  - radius(FWHM): 100  $\mu\text{m}$
  - near Gaussian shape
  - total power : **40 W/(2 $\pi$ sr)**
  - brilliance : **100 W/(mm<sup>2</sup>sr)**



# Measurements around 13.5 nm: Radial Profile

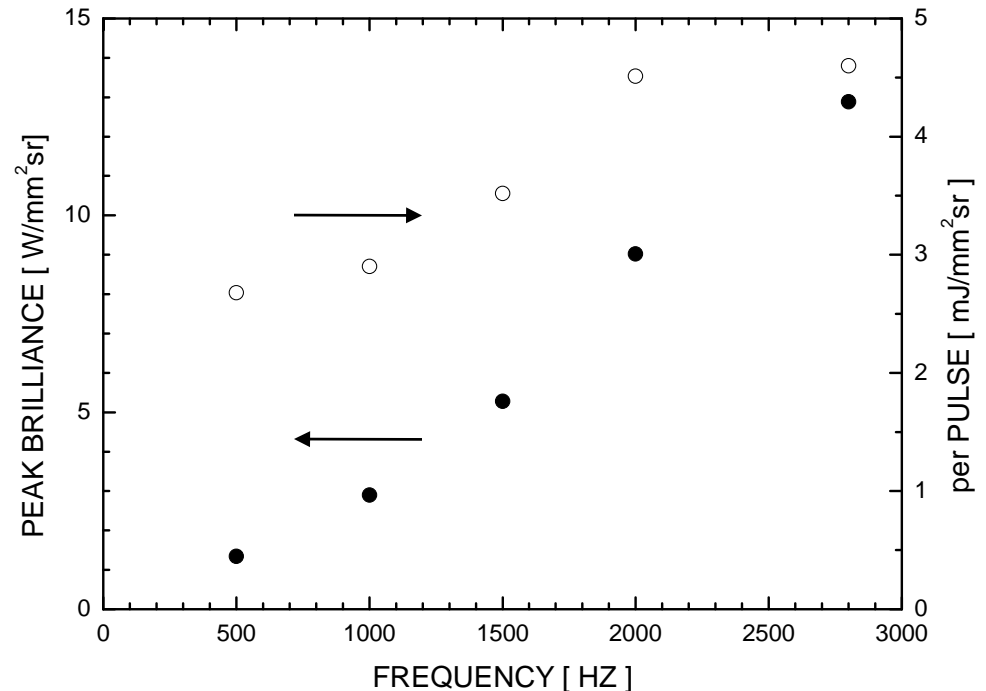
- pulse energy : 3.1 J
- input power : up to 8.7 kW
- no increase of radius with increase of input power
- maximum pulse brilliances at highest input power
- no change of radial profile with input power
- radius (FWHM) :  $\sim 210 \mu\text{m}$



# Measurements around 13.5 nm: Brilliance Scaling

- increase of peak brilliance with higher input power due to higher conversion efficiency
- discharge parameters:
  - frequency : 2800 Hz
  - pulse energy : 3.1 J
  - input power : 8.7 kW
- emission around 13.5 nm into 2% b.w.:

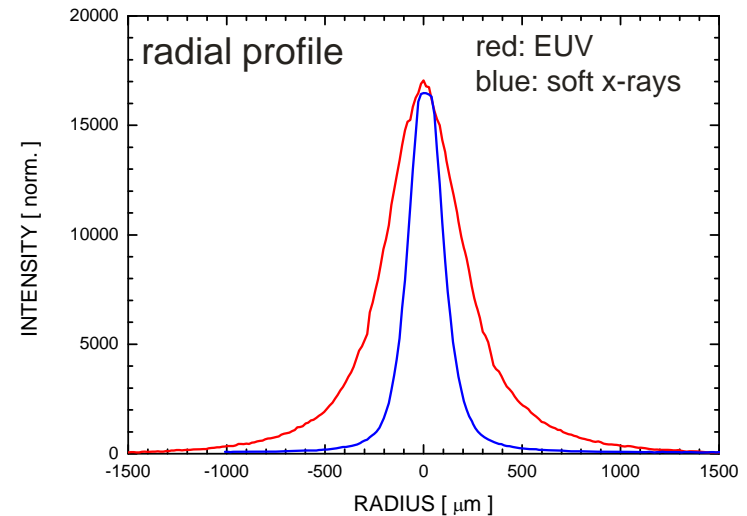
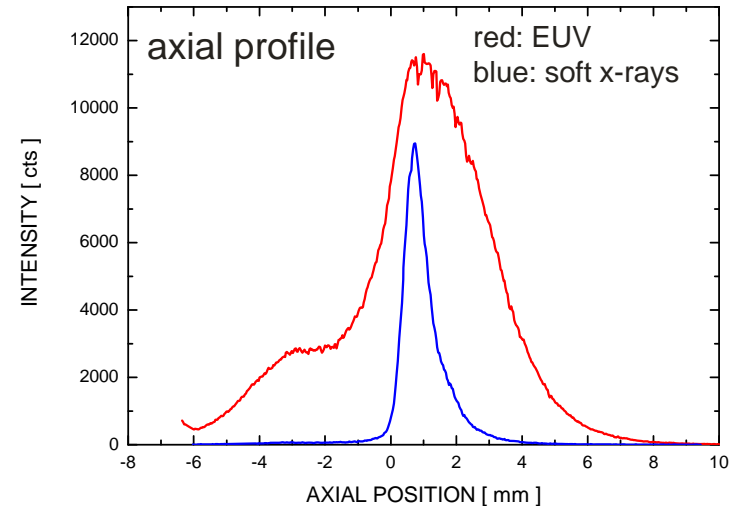
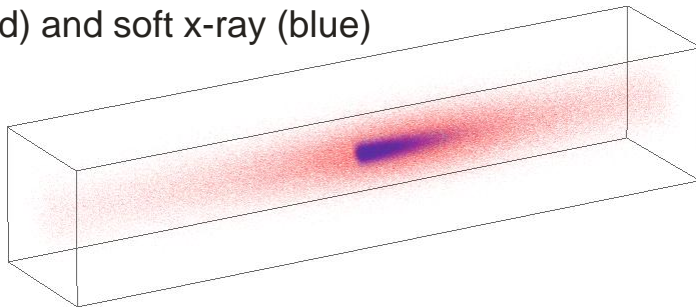
radius(FWHM): 210  $\mu\text{m}$   
close to Lorentzian shape  
total power : **48 W/(2 $\pi$ sr)**  
brilliance : **12.9 W/(mm<sup>2</sup>sr)**



# Xenon discharge: Soft x-ray contribution (1)

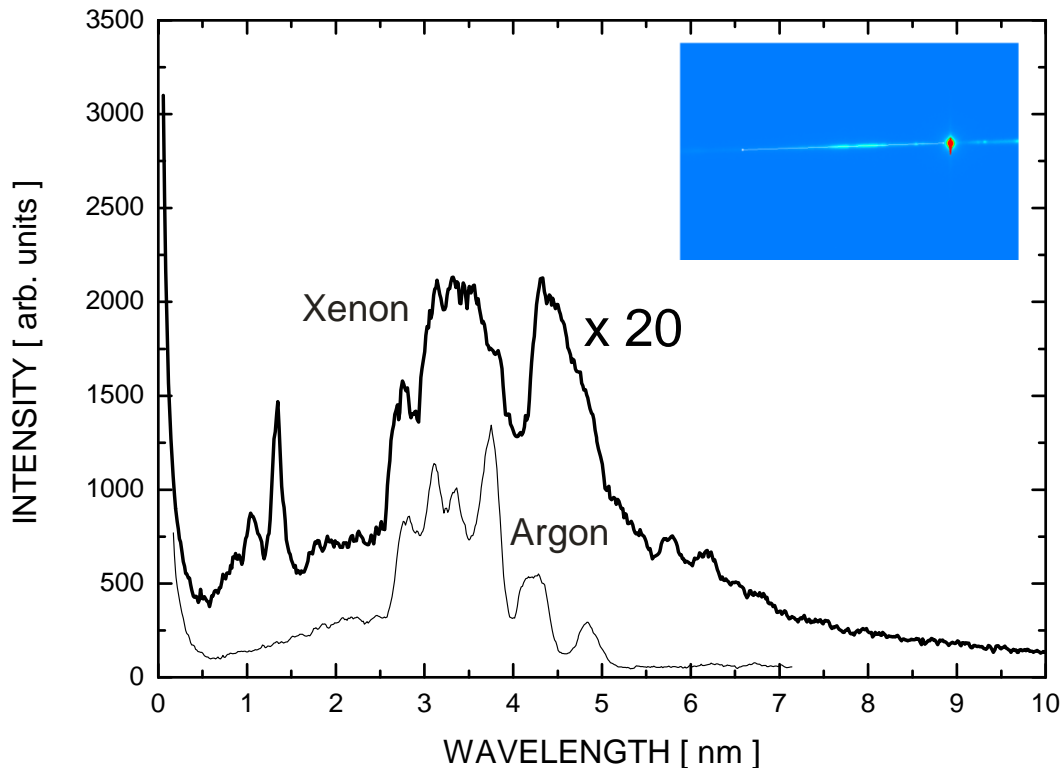
- pulse energy : 3,1 J
- pinhole images for  
soft x-rays (Ti) : ~3 nm  
EUV( $\text{Si}_3\text{N}_4$  + Zr) : 12-16 nm
- observed hot spot  
length : ~ 1 mm  
radius : ~100  $\mu\text{m}$

Simulated distribution of  
EUV (red) and soft x-ray (blue)



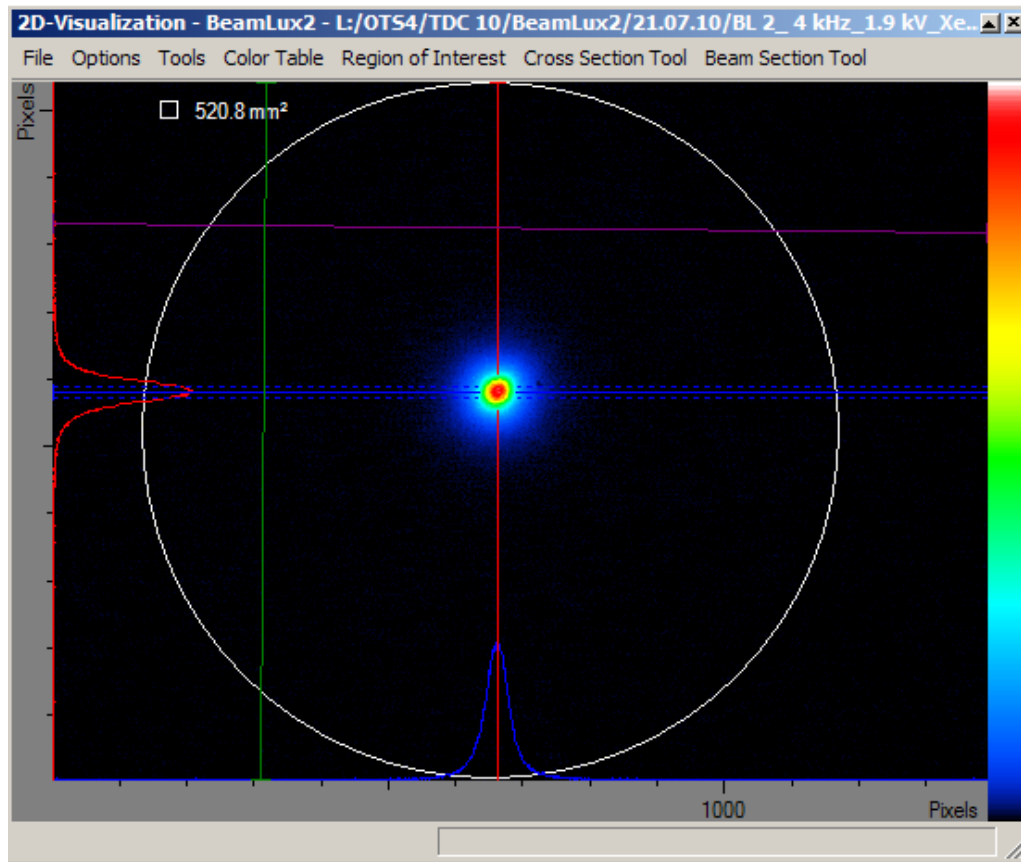


# Xenon discharge: Soft x-ray contribution (2)



- emission spectra observed with pinhole grating spectrograph (low resolution)
- control measurement with Ar
- broadband Xenon emission in water window range
- line emission around 1.4 nm
- hint for highly ionized Xenon and processes leading to small hot spots

# Brilliance of standard Xenon source at Xtreme



$$\int B(x, y) dA = 146 \text{ W} / 2\pi$$

Brilliance B:

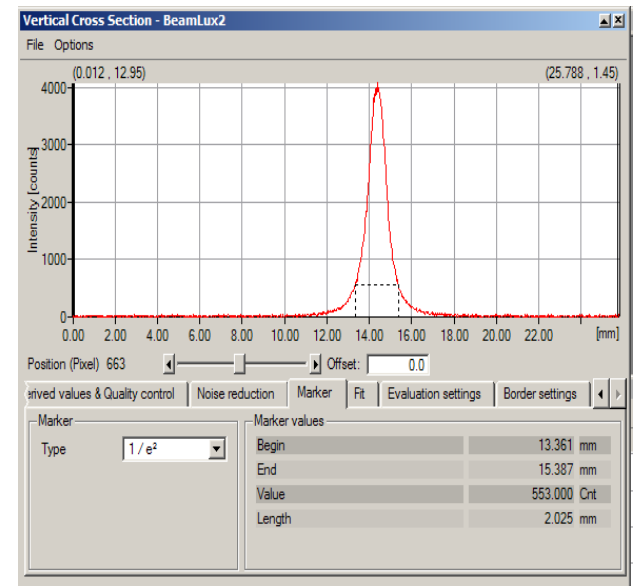
16.5 W / (mm² sr)

into 2% b.w. for 13.5 nm

4 kHz operation , dc ~ 10%

Radial profile (on-axis)

radius (FW1/e²) : ~ 0.8 mm



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# Scaling considerations for 13.5nm (2% b.w.)

		today	extrapolated	Remark
Input Power	kW	8,7	15	by increase of repetition rate and pulse energy
Conversion efficiency	%/(2 $\pi$ sr 2%b.w.)	0,48	0,6	already observed for different discharge conditions
Pinch radius (end-on)	$\mu$ m	210	170	140 $\mu$ m already observed for different discharge conditions
Pinch Profile		appr. Lorentz	Gauss (gain of $\sim 2$ )	currently dividing by $3.7\pi r^2$
Loss due to axial extension		0,8	0,8	for emission into 2.3° (half cone)
Brilliance	W/(mm <sup>2</sup> sr)	12,9	<b>84.0</b>	(losses due to axial extension not included)

Including technical constraints:  **$\sim 40$  W/(mm<sup>2</sup> sr)**  
at 13.5 nm into 2% b.w.

# Next Generation XUV sources at ILT

- same design for covering the range from soft x-rays to extreme ultraviolet
- power supply developed by ILT matched to special requirements for XUV sources
- push-button operation  
( no special trained personal required)

Lamp Head  
(60 cm diameter)



# Conclusions and Summary

- discharge sources exhibit high maturity and are in commercial use
- a range from soft x-ray to extreme ultraviolet can be covered with the same discharge concepts
- work on brilliance scaling just has started
- demonstrated:
  - >100 W/(mm<sup>2</sup> sr) into 4% b.w. for 10.9 nm (ILT)
  - 12.9 W/(mm<sup>2</sup> sr) into 2% b.w. for 13.5 nm (ILT)
  - 16.5 W/(mm<sup>2</sup> sr) into 2% b.w. for 13.5 nm (Xtreme Tech.)
- optimization potential for up to 100 W/(mm<sup>2</sup> sr) for 13.5 nm is identified
- discharge sources are worth for further work on brilliance scaling